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Am ndm nts To Th Claims:

This listing of claims will replace all prior versions and listings of claims in the application:

1. (Currently amended) A plasma processing apparatus comprising:

a process chamber for processing by means of plasma;

microwave transmission means for transmitting microwave to said process chamber;

a dielectric for radiating the microwave transmitted by said microwave transmission means into said process chamber; and

a slot antenna plate formed of conductor, placed on a side, facing said process chamber, of said dielectric, and including an opening for passing the microwave therethrough radiated from said dielectric wherein said opening of said slot antenna has a longer side with its length equal to half the space wavelength of the dielectric.

- 2. (Original) The plasma processing apparatus according to claim 1, wherein said opening of said slot antenna plate is positioned directly below an antinode of a standing wave of the microwave in a resonator constituted of said microwave transmission means and said dielectric.
- 3. (Original) The plasma processing apparatus according to claim 1, wherein said slot antenna plate has its potential adjusted at a ground potential or a positive potential.
- 4. (Original) The plasma processing apparatus according to claim 1, wherein said slot antenna plate includes a channel for processing gas.
- 5. (New) The plasma processing apparatus according to claim 1, wherein the length of the longer side of the opening is varied depending on the size of the standing-wave distribution.